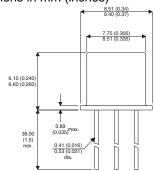


# 2N5015 2N5015S

#### **MECHANICAL DATA**

Dimensions in mm (inches)





# TO5 (TO-205AA) Underside View

PIN 1 - Emitter PIN 2 - Base

PIN 3 - Collector

# HIGH VOLTAGE SILICON EPITAXIAL NPN TRANSISTOR

#### **FEATURES**

- SILICON PLANAR EPITAXIAL NPN TRANSISTOR
- HIGH BREAKDOWN VOLTAGE
- LOW SATURATION VOLTAGE
- HERMETIC TO5 or TO39 ('S' Suffix) PACKAGE
- HI-RELIABILITY SCREENING OPTIONS AVAILABLE

#### **APPLICATIONS**

For high reliability general purpose high voltage switching and linear applications requiring small size and low weight devices.

## ABSOLUTE MAXIMUM RATINGS T<sub>CASE</sub> = 25°C unless otherwise stated

V <sub>CBO</sub>	Collector - Base Voltage	1000V
$V_{CER}$	Collector - Emitter Voltage ( $R_{BE} = 1.0K\Omega$ )	1000V
V <sub>EBO</sub>	Emitter – Base Voltage	5V
I <sub>c</sub>	Continuous Collector Current	0.5A
$P_tot$	Total Power Dissipation $T_{case} = 50^{\circ}C$	2W
	De-rate Linearly $T_{case} > 25^{\circ}C$	20mW/°C
$T_{stg},T_{J}$	Operating and Storage Temperature Range	-55 to +150°C

Semelab Plc reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by Semelab is believed to be both accurate and reliable at the time of going to press. However Semelab assumes no responsibility for any errors or omissions discovered in its use. Semelab encourages customers to verify that datasheets are current before placing orders.

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# 2N5015 2N5015S

### THERMAL CHARACTERISTICS

$R_{ heta_{JC}}$	Thermal Resistance Junction - Case	Max	50	°C/W
$R_{\theta JA}$	Thermal Resistance Junction - Ambient	Max	175	°C/W

### **ELECTRICAL CHARACTERISTICS** (T<sub>case</sub>=25°C unless otherwise stated)

	Parameter	Test Conditions		Min.	Тур.	Max.	Unit
$V_{\text{(BR)CER*}}$	Collector - Emitter Breakdown Voltage	$I_{c} = 100 \mu A$	$R_{BE} = 1.0 K\Omega$	1000	1	-	
$V_{(BR)CBO^{\star}}$	Collector - Base Breakdown Voltage	$I_{c} = 200 \mu A$		1000	-	-	V
$V_{(BR)EBO^{\star}}$	Emitter - Base Breakdown Voltage	$I_c = 0$	$I_{\scriptscriptstyle E} = 50 \mu A$	5.0	-	-	
	Collector - Base Cut-Off Current	V <sub>CB</sub> = 760V		-	-	12	
I <sub>CBO*</sub>			T <sub>CASE</sub> = 100°C	-	10	100	μΑ
I <sub>EBO*</sub>	Emitter - Base Cut-Off Current	$V_{EB} = 4V$		-	-	20	
V <sub>CE(sat)</sub> *	Collector - Emitter Saturation Voltage	I <sub>c</sub> = 20mA	I <sub>B</sub> = 5.0mA	-	-	1.8	V
V <sub>BE(sat)</sub> *	Base - Emitter Saturation Voltage	$I_c = 20mA$	I <sub>B</sub> = 5.0mA	-	-	1.0	V
		$I_c = 5mA$	V <sub>CE</sub> = 10V	10	-	-	
h <sub>FE</sub> *	DC Current Gain	I <sub>c</sub> = 20mA	V <sub>CE</sub> = 10V	30	-	180	
			$T_{CASE} = -55^{\circ}C$	10	-	-	

### **DYNAMIC CHARACTERISTICS** (T\_\_=25°C unless otherwise stated)

f <sub>T</sub>	Transition Frequency	I <sub>c</sub> = 20mA f = 10MHz	V <sub>CE</sub> = 10V	10	-	-	MHz
Сово	Open Circuit Output Capacitance	$I_{E} = 0$ $f = 1.0MHz$	V <sub>CB</sub> = 10V	-	-	30	pF

<sup>\*</sup> Pulse test  $t_0 = 300 \mu s$ ,  $\delta < 2\%$ 

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